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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/001,305	11/30/2001	Stefan Hau-Riege	042390.P12075	2401
. 759		•	EXAM	INER
Mark V. Seele	y FOLOFF, TAYLOR &	HARRISON, MONICA D		
Seventh Floor		ZAFMAN	ART UNIT	PAPER NUMBER
12400 Wilshire			2829	*
Lod Angeles, CA 90025			DATE MAILED: 05/21/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	
Office Action Commence	10/001,305	HAU-RIEGE ET AL.	
Office Action Summary	Examiner	Art Unit	
	Monica D. Harrison	2829	
The MAILING DATE of this communication appeared for Reply	ears on the cover shet with the co	orrespond nce address	
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period with Failure to reply within the set or extended period for reply will, by statute, any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	6(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from to cause the application to become ABANDONED	ely filed will be considered timely. the mailing date of this communication.	
Status		•	
1) Responsive to communication(s) filed on	•	•	
	- action is non-final.		
3) Since this application is in condition for allowant	ce except for formal matters, pro-	secution as to the ments is	
closed in accordance with the practice under Ex			
Disposition of Claims			
4)⊠ Claim(s) <u>1-24</u> is/are pending in the application.			
4a) Of the above claim(s) <u>1-15</u> is/are withdrawn		• •	
5)⊠ Claim(s) <u>16-20</u> is/are allowed.			
6)⊠ Claim(s) <u>21-24</u> is/are rejected.		•	
7) Claim(s) is/are objected to.	3m ·		
8) Claim(s) are subject to restriction and/or	election requirement.		
Application Papers	*		
9) The specification is objected to by the Examiner.	*	· ·	
10) ☐ The drawing(s) filed on 30 October 2001 is/are:		to by the Examinor	
Applicant may not request that any objection to the d			
Replacement drawing sheet(s) including the correction	·		
11) The oath or declaration is objected to by the Exa	· · · · · · · · · · · · · · · · · · ·		
Priority under 35 U.S.C. § 119		·	
12) Acknowledgment is made of a claim for foreign part a) All b) Some * c) None of:	priority under 35 U.S.C. § 119(a)-	(d) or (f).	
1. Certified copies of the priority documents	have been received.		
2. Certified copies of the priority documents	•	n No.	
3. ☐ Copies of the certified copies of the priorit		·	
application from the International Bureau			
* See the attached detailed Office action for a list o	f the certified copies not received	i.	
in the state of th	m is being to be a second way in the color, a fin		
Attachment(s)			
1) Notice of References Cited (PTO-892)	4) Interview Summary (
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	Paper No(s)/Mail Dat 5) Notice of Informal Pa 6) Other:		
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DETAILED ACTION

1. The amendment filed 2/24/2004 has been entered.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 21 and 22 are rejected under 35 U.S.C. 102(b) as being anticipated by Yang et al (6,297,147 B1).

- Regarding claim 21, Yang et al discloses a method of making a semiconductor device comprising: forming a dielectric layer on a substrate (Figure 3, reference 20); etching a via through the dielectric layer and a trench into the dielectric layer (Figure 2, reference 26); filling the via and trench with a conductive layer (Figure 3, reference 22); exposing a portion of the conductive layer that lies above the via; and introducing a dopant into the exposed portion of the conductive layer (Figure 3, reference 28).
- 3. Regarding claim 22, Yang et al discloses wherein the dopant is introduced into the exposed portion of the conductive layer by depositing a dopant containing layer onto the exposed portion (Figure 4, reference 30).

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Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 23 and 24 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yang et al (6,297,147 B1) in view of Lam et al (5,185,294).

4. Yang et al discloses all claimed subject matter except wherein the dopant is introduced into the exposed portion of the conductive layer by ion implanting the dopant into the exposed portion (claim 23) and wherein the dopant is introduced into the exposed portion of the conductive layer by subjecting that exposed portion to a gas that contains the dopant (claim 24).

Lam et al discloses wherein the dopant is introduced into the exposed portion of the conductive layer by ion implanting the dopant into the exposed portion (column 6, lines 11-28) and wherein the dopant is introduced into the exposed portion of the conductive layer by subjecting that exposed portion to a gas that contains the dopant (column 6, lines 29-68 thru column 7, lines 1-29).

Since Yang et al and Lam et al are both from the same field of endeavor, the purpose disclosed by Lam et al would have been recognized in the pertinent art of Yang et al.

It would have been obvious, at the time the invention was made, to one with ordinary skill in the art, to modify Yang et al with the teachings of Lam et al for the purpose of controlling doping by using high dose ion implantation which will decrease oxidation shorts.

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Allowable Subject Matter

5. Claims 16-20 are allowed over the prior art of record.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Monica D. Harrison whose telephone number is 571-272-1959. The examiner can normally be reached on M-F 7:00am-3:30pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Kammie Cuneo can be reached on 571-272-1957. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-A197 (toll-free).

Monica D. Harrison AU 2829

Mdh April 29, 2004

KAMAND CUNEO
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800